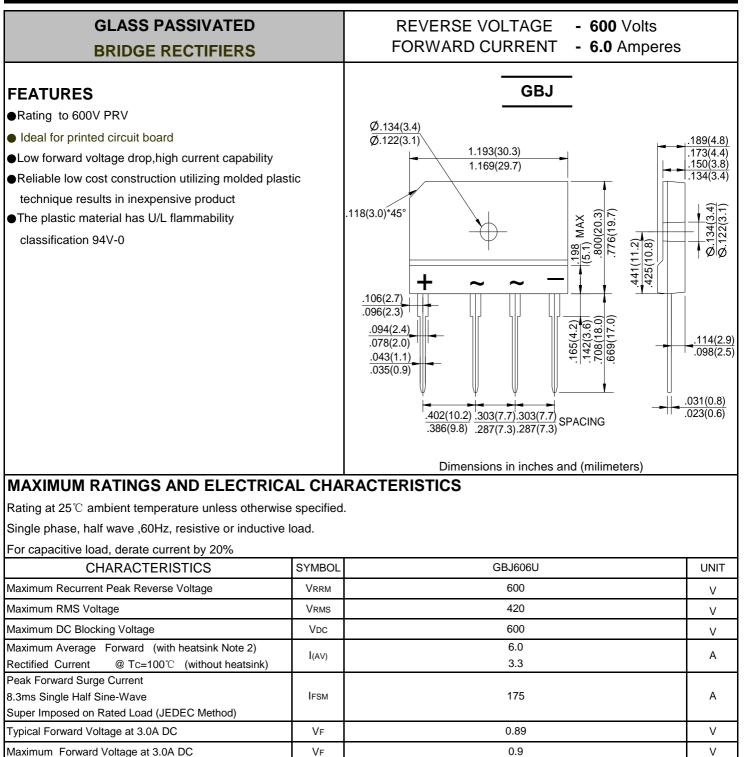


GBJ606U



IR at Rated DC Blocking Voltage @ TJ=125℃ 500 l²t 127 I²t Rating for Fusing (t<8.3ms) Typical Junction Capacitance Per Element (Note1) CJ 55 1.8 Typical Thermal Resistance Rejc ТJ -55 to +150 Operating Temperature Range -55 to +150 Storage Temperature Range TSTG

NOTES: 1.Measured at 1.0MHz and applied reverse voltage of 4.0V DC.

Maximum DC Reverse Current

2.Device mounted on 75mm*75mm*1.6mm Cu plate heatsink.

@ TJ=25℃

3.The typical data above is for reference only(典型值仅供参考).

μA

A²s

pF

°C/W

°C

°C

10.0

RATING AND CHARACTERTIC CURVES GBJ606U

6.0

5.0

4.0

3.0

2.0

1.0

0.00

100

CAPACITANCE, (pF)

10

1.0

1.0

0

20

TJ=25°C,f=1MHz

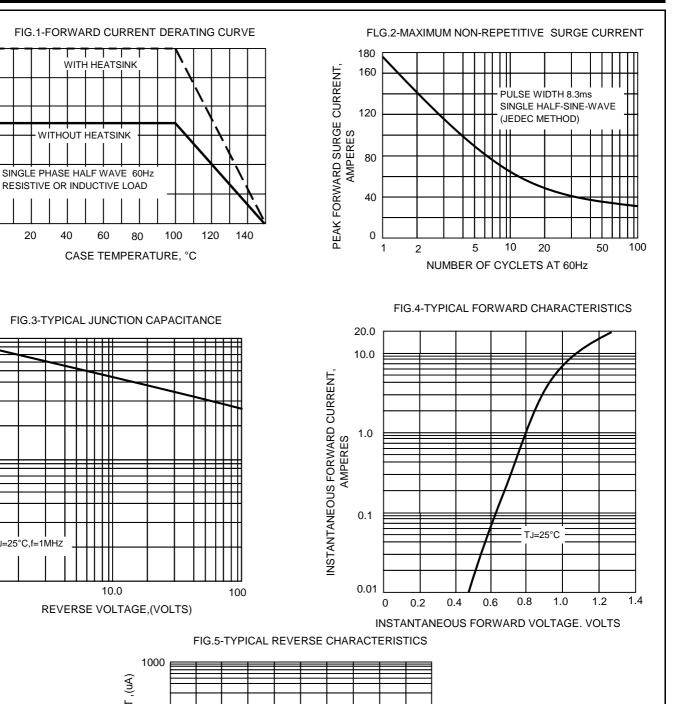
40

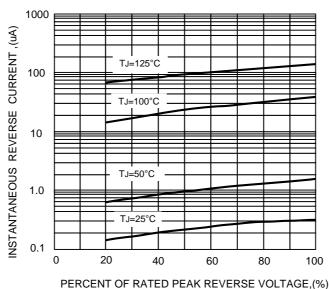
60

10.0

AVERAGE FORWARD CURRENT

AMPERES





The cruve graph is for reference only, can't be the basis for judgment(曲线图仅供参考)!

REV. 2, 18-Aug-2015